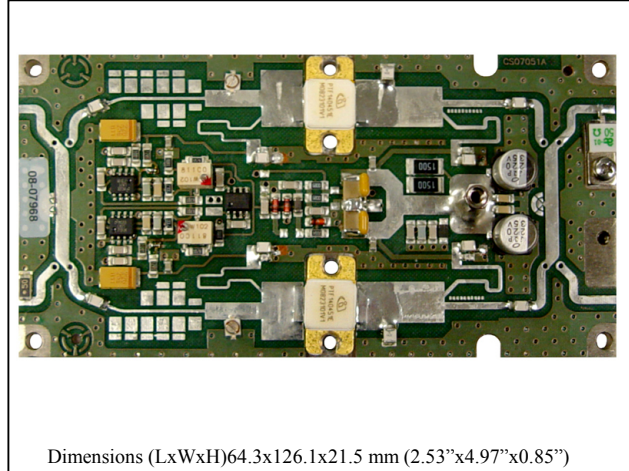


80W DAB LDMos Technology

Designed for Digital Audio Broadcasting, this amplifier incorporates microstrip technology and push-pull LDMos Devices to enhance ruggedness and reliability.

- 1450 - 1500 MHz
- (28 ±32 V) 30V Nominal
- Input/Output 50 Ω - 50 Ω
- P_{out} : 80W CW
80Wrms DAB
Shoulder ≤ - 28 dB
- Gain : 14 dB min
- Class AB
- Devices: PTF140451 or equivalent
- Connectorized version available



This picture is a mere example, it does not bind the provided product

ABSOLUTE MAXIMUM RATINGS (Device Flange T = 70 °C)

Symbol	Parameter	Value	Unit
V _S	Voltage Supply	35	V dc
I _S	Current Supply	25	A dc
T _{stg}	Storage Temperature Range	-30 + 100	°C
T _c	Operating Base Plate Temperature	0 + 75 ¹	°C
ψ	VSWR max	3:1 all phase angle	-
	Max input power	See note ²	-

ELECTRICAL SPECIFICATIONS (Base Plate T. = 45 °C, 50Ω loaded, V_d = 30 V)

Symbol	Parameter	Test Conditions	Value			Unit
			Min	Typ.	Max	
BW	Bandwidth	P _{out} = 200 W (CW)	1450		1500	MHz
G _p	Power gain	P _{ref} = 50 W (CW)	14	15	-	dB
P _{out} - 1dB	Power Output @ 1dB Compression	Referred to P _{out} = 50W (CW)	80	170	-	W
I _q *	Quiescent Current	P _{out} = 0 W - Total ³ *	-	-	4	A
I _{tot} *	@ P _{Max}		-		20	A
I _{rl}	Input return loss	P _{out} = 80 W CW	18	20	-	dB
ψ	Load mismatch	P _{ref} = 80 W CW, f= 1500MHz, load VSWR = 2:1, all phase angles	No degradation in P _{out}			
Gr	Gain Flatness	P _{ref} = 80W CW, BW: 1450-1500MHz		±0.5	±1	dB
η	Drain Efficiency	P _{out} = 80 W (CW)	35	45	-	%

¹ Warning: The base plate temperature must be 75 °C max, using an appropriate Heatsink.

² The input power must not exceed +6dB, for 1 microsec. , the nominal input power referred to the 1dBcp power output.

³ The Quiescent Current is set at typical value, in factory. This parameter can be adjusted by the final user depending on the applied signal and/or frequency and output power.

(Warning: Do not exceed the specified max I_q value).

* Depending of handling signal (analog /digital)